

256K x 16 Bit 3.3 V Asynchronous Fast Static RAM

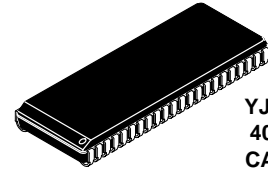
The MCM6343 is a 4,194,304-bit static random access memory organized as 262,144 words of 16 bits. Static design eliminates the need for external clocks or timing strobes.

The MCM6343 is equipped with chip enable (\bar{E}), write enable (\bar{W}), and output enable (\bar{G}) pins, allowing for greater system flexibility and eliminating bus contention problems. Separate byte enable controls ($\bar{L}B$ and $\bar{U}B$) allow individual bytes to be written and read. $\bar{L}B$ controls the lower bits DQL [7:0], while $\bar{U}B$ controls the upper bits DQU [7:0].

The MCM6343 is available in a 400 mil, 44-lead small-outline SOJ package and a 44-lead TSOP Type II package.

- Single 3.3 V Power Supply
- Fast Access Time: 10/11/12/15 ns
- Equal Address and Chip Enable Access Time
- All Inputs and Outputs are TTL Compatible
- Data Byte Control
- Fully Static Operation
- Power Operation: 200/195/190/180 mA Maximum, Active AC
- Commercial (0°C to 70°C) and Industrial Temperature (-40 to 85°C) Options

MCM6343



YJ PACKAGE
400 MIL SOJ
CASE 919-01

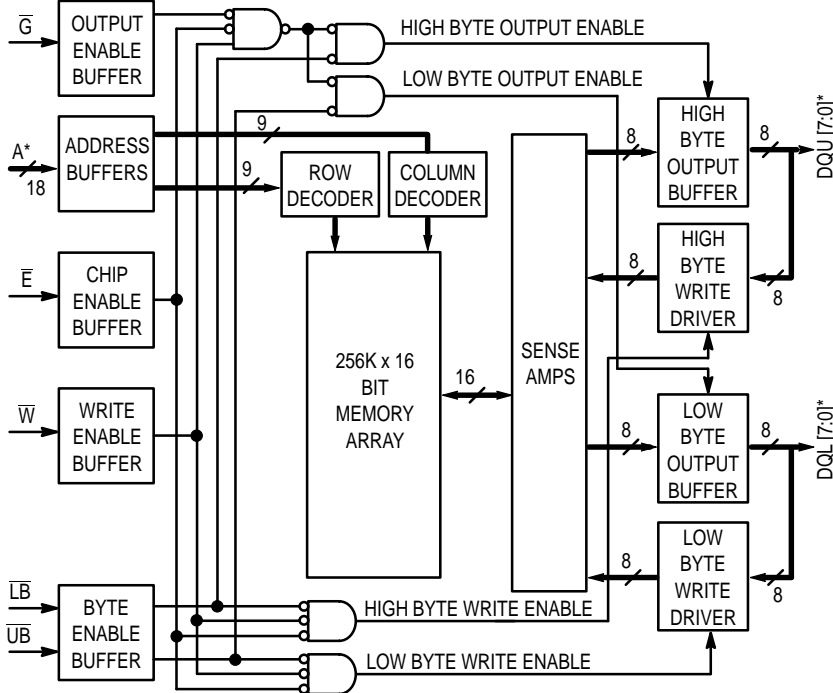


TS PACKAGE
TSOP TYPE II
CASE 924A-02

PIN ASSIGNMENT

A	1	44	A
A	2	43	A
A	3	42	A
A	4	41	\bar{G}
A	5	40	$\bar{U}B$
\bar{E}	6	39	$\bar{L}B$
DQL	7	38	DQU
DQL	8	37	DQU
DQL	9	36	DQU
DQL	10	35	DQU
VDD	11	34	VSS
VSS	12	33	VDD
DQL	13	32	DQU
DQL	14	31	DQU
DQL	15	30	DQU
DQL	16	29	DQU
\bar{W}	17	28	NC
A	18	27	A
A	19	26	A
A	20	25	A
A	21	24	A
A	22	23	A

BLOCK DIAGRAM



* Address (A) and Data (DQU, DQL) signals are assigned by customer, such that PCB layout is optimized for a given design.

PIN NAMES

A [17:0]	Address Input
\bar{E}	Chip Enable
\bar{W}	Write Enable
\bar{G}	Output Enable
$\bar{U}B$	Upper Byte Select
$\bar{L}B$	Lower Byte Select
DQL [7:0]	Data I/O, Low Byte
DQU [7:0]	Data I/O, High Byte
VDD	+ 3.3 V Power Supply
VSS	Ground
NC	No Connection

TRUTH TABLE (X = Don't Care)

\bar{E}	\bar{G}	\bar{W}	LB	\bar{UB}	Mode	V_{DD} Current	DQL [7:0]	DQU [7:0]
H	X	X	X	X	Not Selected	ISB1, ISB2	High-Z	High-Z
L	H	H	X	X	Output Disabled	I _{DDA}	High-Z	High-Z
L	X	X	H	H	Output Disabled	I _{DDA}	High-Z	High-Z
L	L	H	L	H	Low Byte Read	I _{DDA}	D _{out}	High-Z
L	L	H	H	L	High Byte Read	I _{DDA}	High-Z	D _{out}
L	L	H	L	L	Word Read	I _{DDA}	D _{out}	D _{out}
L	X	L	L	H	Low Byte Write	I _{DDA}	D _{in}	High-Z
L	X	L	H	L	High Byte Write	I _{DDA}	High-Z	D _{in}
L	X	L	L	L	Word Write	I _{DDA}	D _{in}	D _{in}

ABSOLUTE MAXIMUM RATINGS (See Notes)

Rating	Symbol	Value	Unit
Supply Voltage	V_{DD}	- 0.5 to 4.6	V
Voltage on Any Pin	V_{in}	- 0.5 to $V_{DD} + 0.5$	V
Output Current per Pin	I_{out}	± 20	mA
Package Power Dissipation	P_D	TBD	W
Temperature Under Bias	T_{bias}	Commercial Industrial - 10 to 85 - 45 to 90	°C
Operating Temperature	T_A	Commercial Industrial 0 to 70 - 45 to 85	°C
Storage Temperature	T_{stg}	- 55 to 150	°C

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to these high-impedance circuits.

This CMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow of at least 500 linear feet per minute is maintained.

NOTES:

1. Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.
2. All voltages are referenced to V_{SS} .
3. Power dissipation capability will be dependent upon package characteristics and use environment.

PRODUCT CONFIGURATIONS

Part Number	Commercial	Industrial	Power Supply	
			+ 10%, - 5%	± 10%
MCM6343YJ10B & MCM6343YJ10BR	✓		✓	
MCM6343YJ11 & MCM6343YJ11R	✓			✓
MCM6343YJ12 & MCM6343YJ12R	✓			✓
MCM6343YJ15 & MCM6343YJ15R	✓			✓
MCM6343TS10B & MCM6343TS10BR	✓		✓	
MCM6343TS11 & MCM6343TS11R	✓			✓
MCM6343TS12 & MCM6343TS12R	✓			✓
MCM6343TS15 & MCM6343TS15R	✓			✓
SCM6343YJ11A & SCM6343YJ11AR		✓		✓
SCM6343YJ12A & SCM6343YJ12AR		✓		✓
SCM6343YJ15A & SCM6343YJ15AR		✓		✓
SCM6343TS11A & SCM6343TS11AR		✓		✓
SCM6343TS12A & SCM6343TS12AR		✓		✓
SCM6343TS15A & SCM6343TS15AR		✓		✓

DC OPERATING CONDITIONS AND CHARACTERISTICS

($V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$, $T_A = 0\text{ to }70^\circ\text{C}$, $V_{DD} = 3.3\text{ V} + 0.3\text{ V}$, -0.15 V for 10 ns Device)
 ($T_A = -40\text{ to }85^\circ\text{C}$ for Industrial Temperature Option)

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Typ	Max	Unit
Power Supply Voltage	V_{DD}	3	3.3	3.6	V
Input High Voltage	V_{IH}	2.2	—	$V_{DD} + 0.3^{**}$	V
Input Low Voltage	V_{IL}	-0.5^*	—	0.8	V

* $V_{IL}(\text{min}) = -0.5\text{ V}$ dc; $V_{IL}(\text{min}) = -2.0\text{ V}$ ac (pulse width $\leq 20\text{ ns}$) for $I \leq 20.0\text{ mA}$.

** $V_{IH}(\text{max}) = V_{DD} + 0.3\text{ V}$ dc; $V_{IH}(\text{max}) = V_{DD} + 2.0\text{ V}$ ac (pulse width $\leq 20\text{ ns}$) for $I \leq 20.0\text{ mA}$.

DC CHARACTERISTICS

Parameter	Symbol	Min	Max	Unit
Input Leakage Current (All Inputs, $V_{in} = 0\text{ to }V_{DD}$)	$I_{lkg}(I)$	—	± 1	μA
Output Leakage Current ($\bar{E} = V_{IH}$, $V_{out} = 0\text{ to }V_{DD}$)	$I_{lkg}(O)$	—	± 1	μA
Output Low Voltage ($I_{OL} = +4\text{ mA}$) ($I_{OL} = +100\text{ }\mu\text{A}$)	V_{OL}	—	0.4 $V_{SS} + 0.2$	V
Output High Voltage ($I_{OH} = -4\text{ mA}$) ($I_{OH} = -100\text{ }\mu\text{A}$)	V_{OH}	2.4 $V_{DD} - 0.2$	—	V

POWER SUPPLY CURRENTS

Parameter	Symbol	0 to 70°C	-40 to 85°C	Unit
AC Active Supply Current ($I_{out} = 0\text{ mA}$, $V_{CC} = \text{Max}$) MCM6343-10: $t_{AVAV} = 10\text{ ns}$ MCM6343-11: $t_{AVAV} = 11\text{ ns}$ MCM6343-12: $t_{AVAV} = 12\text{ ns}$ MCM6343-15: $t_{AVAV} = 15\text{ ns}$	I_{CC}	200 195 190 180	260 255 250 240	mA
AC Standby Current ($V_{CC} = \text{Max}$, $\bar{E} = V_{IH}$, No Other Restrictions on Other Inputs) MCM6343-10: $t_{AVAV} = 10\text{ ns}$ MCM6343-11: $t_{AVAV} = 11\text{ ns}$ MCM6343-12: $t_{AVAV} = 12\text{ ns}$ MCM6343-15: $t_{AVAV} = 15\text{ ns}$	I_{SB1}	45 40 35 30	55 55 55 50	mA
CMOS Standby Current ($\bar{E} \geq V_{CC} - 0.2\text{ V}$, $V_{in} \leq V_{SS} + 0.2\text{ V}$ or $\geq V_{CC} - 0.2\text{ V}$) ($V_{CC} = \text{Max}$, $f = 0\text{ MHz}$)	I_{SB2}	8	10	mA

CAPACITANCE ($f = 1.0\text{ MHz}$, $dV = 3.0\text{ V}$, $T_A = 25^\circ\text{C}$, Periodically Sampled Rather Than 100% Tested)

Parameter	Symbol	Typ	Max	Unit
Address Input Capacitance	C_{in}	—	6	pF
Control Input Capacitance	C_{in}	—	6	pF
Input/Output Capacitance	$C_{I/O}$	—	8	pF

AC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 3.3 V ± 0.3 V, T_A = 0 to 70°C, V_{DD} = 3.3 V + 0.3 V, - 0.15 V for 10 ns Device)
(T_A = - 40 to 85°C for Industrial Temperature Option)

Logic Input Timing Measurement Reference Level 1.50 V
Logic Input Pulse Levels 0 to 3.0 V
Input Rise/Fall Time 2 ns

Output Timing Reference Level 1.50 V
Output Load See Figure 1

READ CYCLE TIMING (See Notes 1, 2, and 3)

Parameter	Symbol	MCM6343-10		MCM6343-11		MCM6343-12		MCM6343-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Read Cycle Time	t _{AVAV}	10	—	11	—	12	—	15	—	ns	4
Address Access Time	t _{AVQV}	—	10	—	11	—	12	—	15	ns	
Enable Access Time	t _{ELQV}	—	10	—	11	—	12	—	15	ns	5
Output Enable Access Time	t _{GLQV}	—	4	—	4	—	4	—	5	ns	
Output Hold from Address Change	t _{AXQX}	3	—	3	—	3	—	3	—	ns	
Enable Low to Output Active	t _{ELQX}	3	—	3	—	3	—	3	—	ns	6, 7, 8
Output Enable Low to Output Active	t _{GLQX}	0	—	0	—	0	—	0	—	ns	6, 7, 8
Enable High to Output High-Z	t _{EHQZ}	0	5	0	6	0	6	0	7	ns	6, 7, 8
Output Enable High to Output High-Z	t _{GHQZ}	0	4	0	4	0	4	0	5	ns	6, 7, 8
Byte Enable Access Time	t _{BLQV}	—	5	—	6	—	6	—	7	ns	
Byte Enable Low to Output Active	t _{BLQX}	0	—	0	—	0	—	0	—	ns	6, 7, 8
Byte High to Output High-Z	t _{BHQZ}	0	5	0	6	0	6	0	7	ns	6, 7, 8

NOTES:

1. \overline{W} is high for read cycle.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. Device is continuously selected ($\overline{E} \leq V_{IL}$, $\overline{G} \leq V_{IL}$).
4. All read cycle timings are referenced from the last valid address to the first transitioning address.
5. Addresses valid prior to or coincident with \overline{E} going low.
6. At any given voltage and temperature, t_{EHQZ} max < t_{ELQX} min, and t_{GHQZ} max < t_{GLQX} min, both for a given device and from device to device.
7. This parameter is sampled and not 100% tested.
8. Transition is measured ± 200 mV from steady-state voltage.

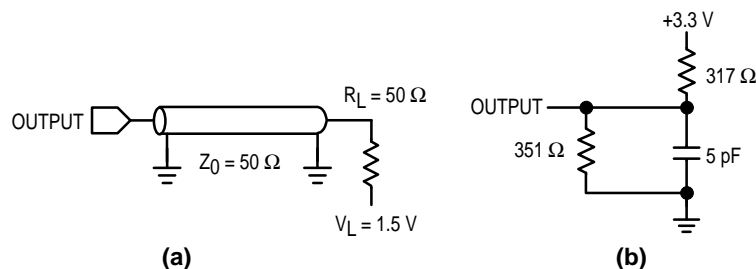


Figure 1. AC Test Loads

TIMING LIMITS

The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time. On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

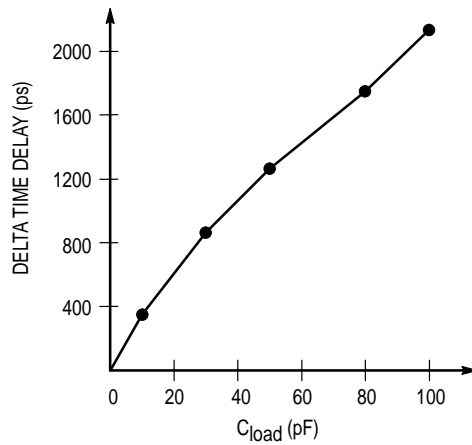
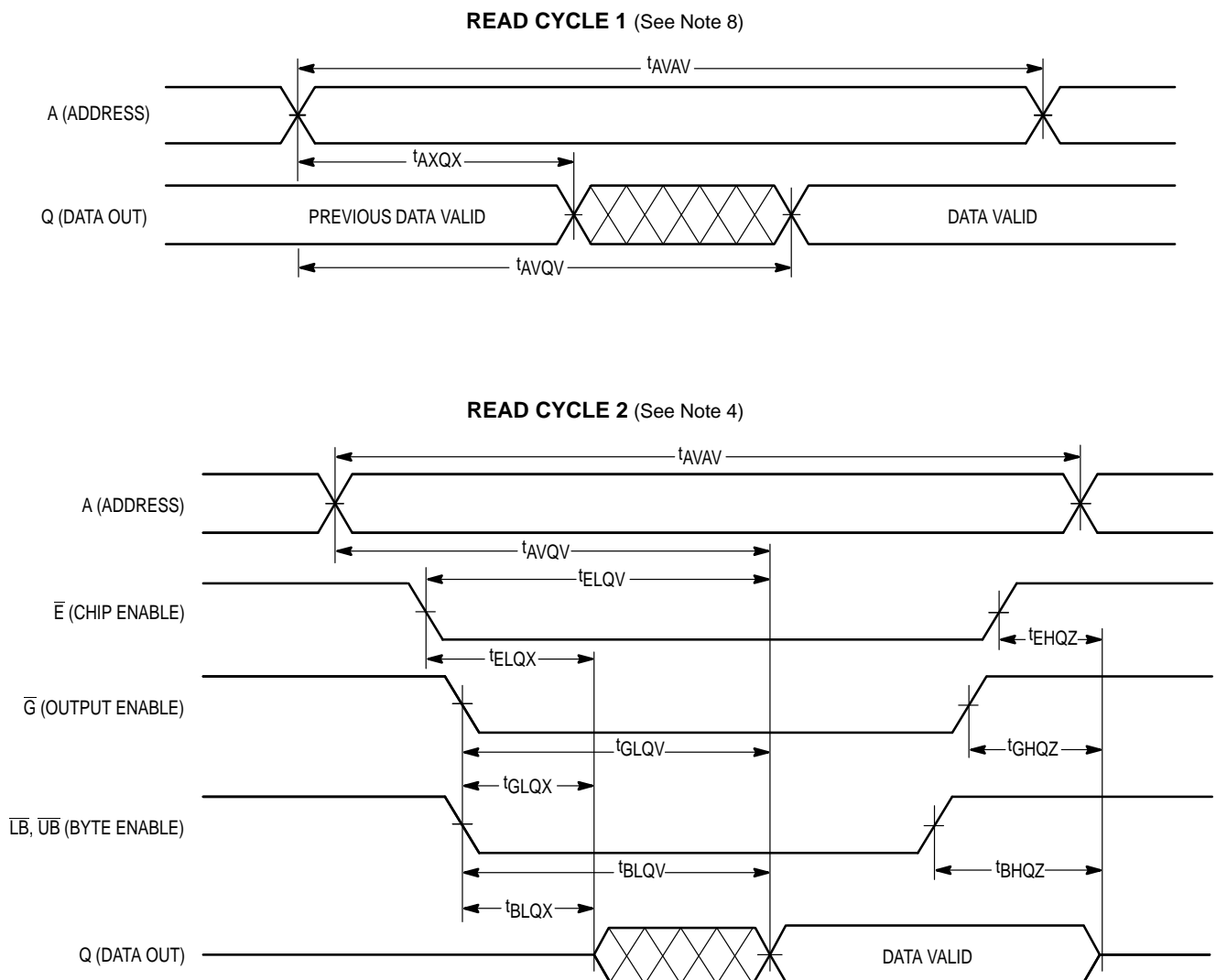


Figure 2. Typical I/O Derating Curve

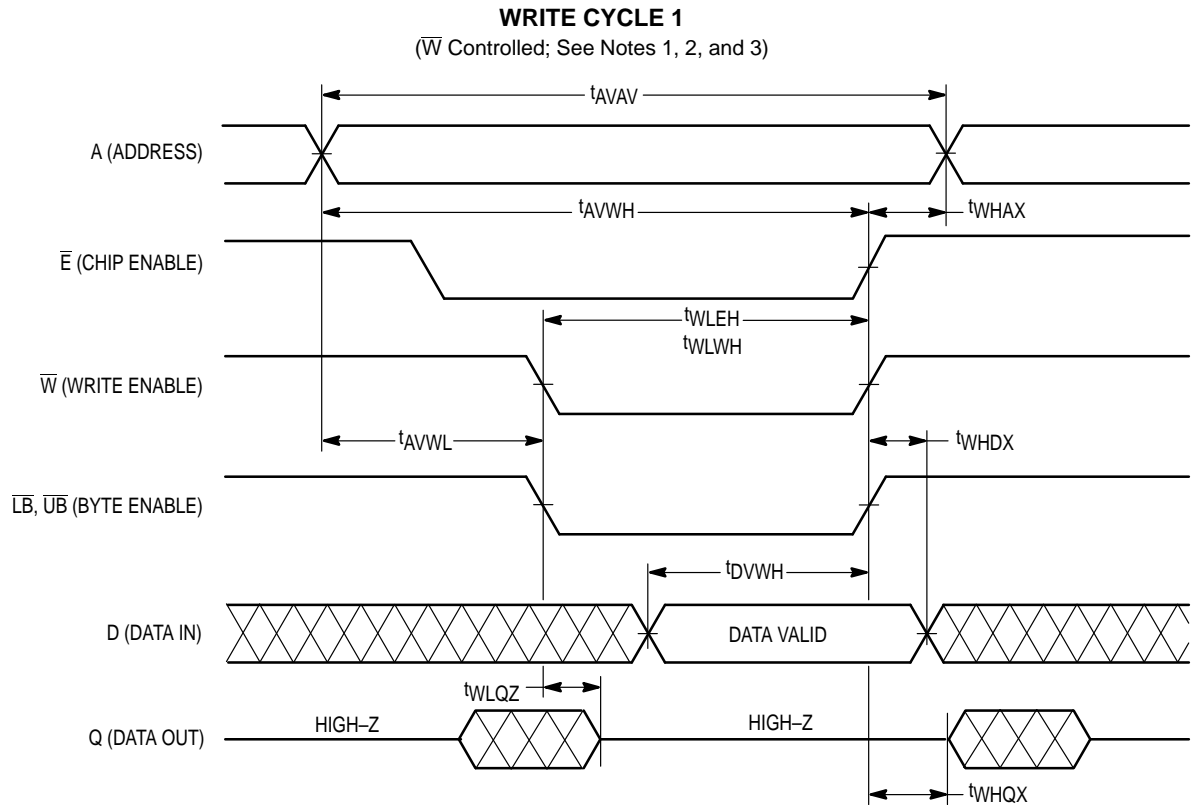


WRITE CYCLE 1 (\overline{W} Controlled; See Notes 1, 2, and 3)

Parameter	Symbol	MCM6343-10		MCM6343-11		MCM6343-12		MCM6343-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	10	—	11	—	12	—	15	—	ns	4
Address Setup Time	t_{AVWL}	0	—	0	—	0	—	0	—	ns	
Address Valid to End of Write	t_{AVWH}	7	—	8	—	8	—	10	—	ns	
Address Valid to End of Write (\overline{G} High)	t_{AVWH}	8	—	9	—	9	—	10	—	ns	
Write Pulse Width	t_{WLWH} t_{WLEH}	9	—	10	—	10	—	12	—	ns	
Write Pulse Width (\overline{G} High)	t_{WLWH} t_{WLEH}	8	—	9	—	9	—	10	—	ns	
Data Valid to End of Write	t_{DVWH}	5	—	6	—	6	—	7	—	ns	
Data Hold Time	t_{WHDX}	0	—	0	—	0	—	0	—	ns	
Write Low to Data High-Z	t_{WLQZ}	0	5	0	6	0	6	0	7	ns	5, 6, 7
Write High to Output Active	t_{WHQX}	3	—	3	—	3	—	3	—	ns	5, 6, 7
Write Recovery Time	t_{WHAX}	0	—	0	—	0	—	0	—	ns	

NOTES:

1. A write occurs during the overlap of \overline{E} low and \overline{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. If \overline{G} goes low coincident with or after \overline{W} goes low, the output will remain in a high-impedance state.
4. All write cycle timings are referenced from the last valid address to the first transitioning address.
5. This parameter is sampled and not 100% tested.
6. Transition is measured ± 200 mV from steady-state voltage.
7. At any given voltage and temperature, t_{WLQZ} max < t_{WHQX} min both for a given device and from device to device.

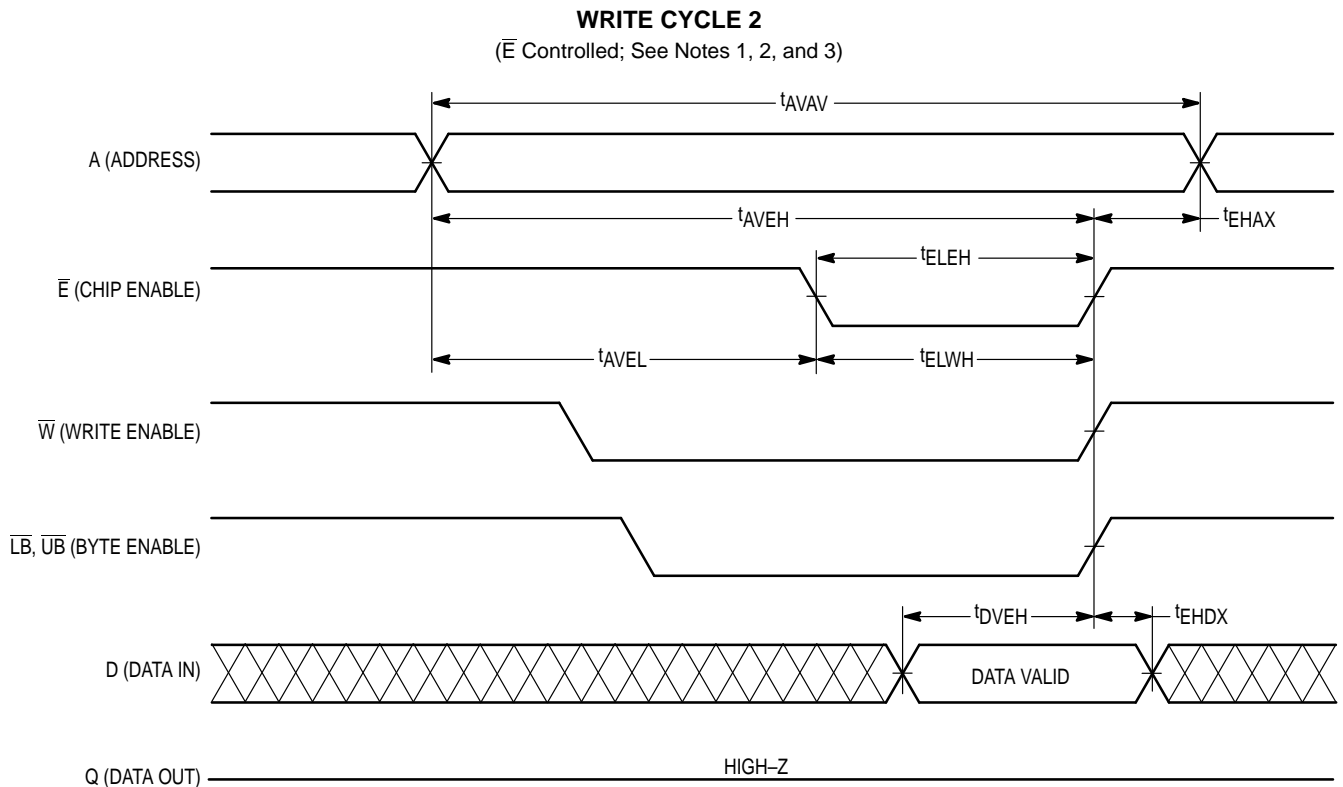


WRITE CYCLE 2 (\bar{E} Controlled; See Notes 1, 2, and 3)

Parameter	Symbol	MCM6343-10		MCM6343-11		MCM6343-12		MCM6343-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	10	—	11	—	12	—	15	—	ns	4
Address Setup Time	t_{AVEL}	0	—	0	—	0	—	0	—	ns	
Address Valid to End of Write	t_{AVEH}	9	—	10	—	10	—	12	—	ns	
Address Valid to End of Write (\bar{G} High)	t_{AVEH}	8	—	9	—	9	—	10	—	ns	
Enable to End of Write	t_{ELEH} , t_{ELWH}	9	—	10	—	10	—	12	—	ns	5, 6
Enable to End of Write (\bar{G} High)	t_{ELEH} , t_{ELWH}	8	—	9	—	9	—	10	—	ns	5, 6
Data Valid to End of Write	t_{DVEH}	5	—	6	—	6	—	7	—	ns	
Data Hold Time	t_{EHDX}	0	—	0	—	0	—	0	—	ns	
Write Recovery Time	t_{EHAX}	0	—	0	—	0	—	0	—	ns	

NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. If \bar{G} goes low coincident with or after \bar{W} goes low, the output will remain in a high-impedance state.
4. All write cycle timing is referenced from the last valid address to the first transitioning address.
5. If \bar{E} goes low coincident with or after \bar{W} goes low, the output will remain in a high-impedance condition.
6. If \bar{E} goes high coincident with or before \bar{W} goes high, the output will remain in a high-impedance condition.

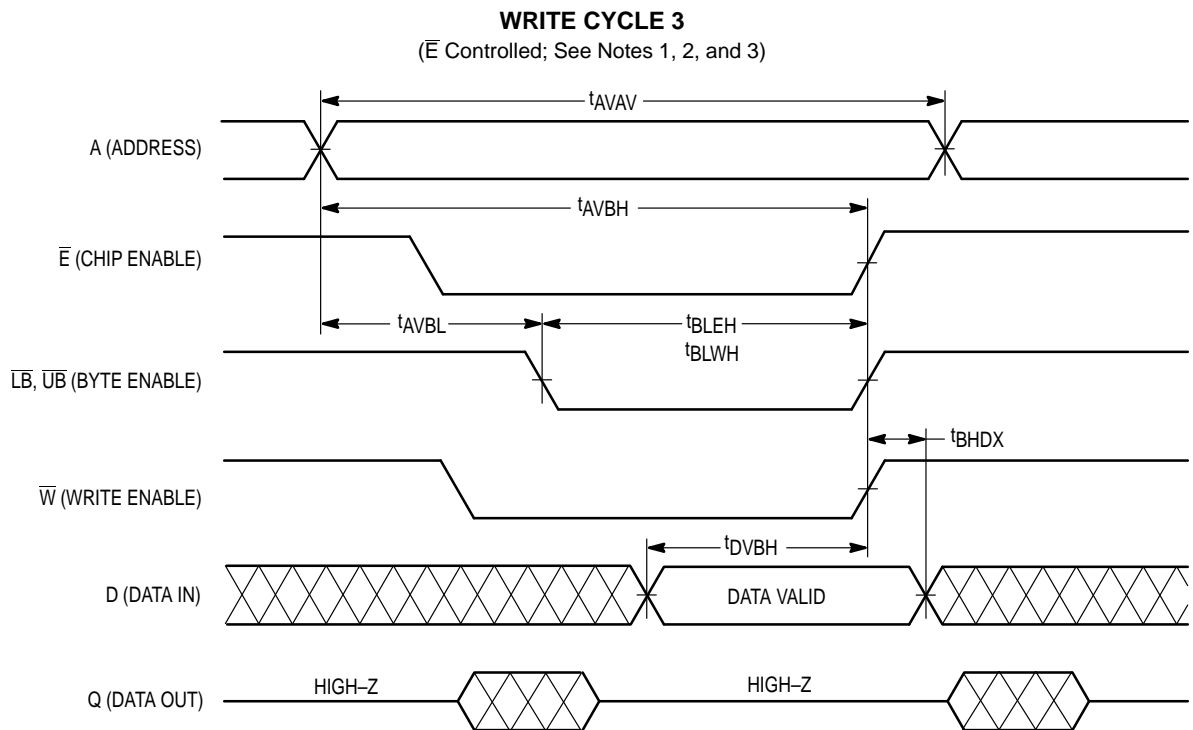


WRITE CYCLE 3 (\bar{E} Controlled; See Notes 1, 2, and 3)

Parameter	Symbol	MCM6343-10		MCM6343-11		MCM6343-12		MCM6343-15		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write Cycle Time	t_{AVAV}	10	—	11	—	12	—	15	—	ns	4
Address Setup Time	t_{AVBL}	0	—	0	—	0	—	0	—	ns	
Address Valid to End of Write	t_{AVBH}	9	—	10	—	10	—	12	—	ns	
Address Valid to End of Write (\bar{G} High)	t_{AVBH}	8	—	9	—	9	—	10	—	ns	
Byte Pulse Width	t_{BLWH} t_{BLEH}	9	—	10	—	10	—	12	—	ns	
Byte Pulse Width (\bar{G} High)	t_{BLWH} t_{BLEH}	8	—	9	—	9	—	10	—	ns	
Data Valid to End of Write	t_{DVBH}	5	—	6	—	6	—	7	—	ns	
Data Hold Time	t_{BHDX}	0	—	0	—	0	—	0	—	ns	

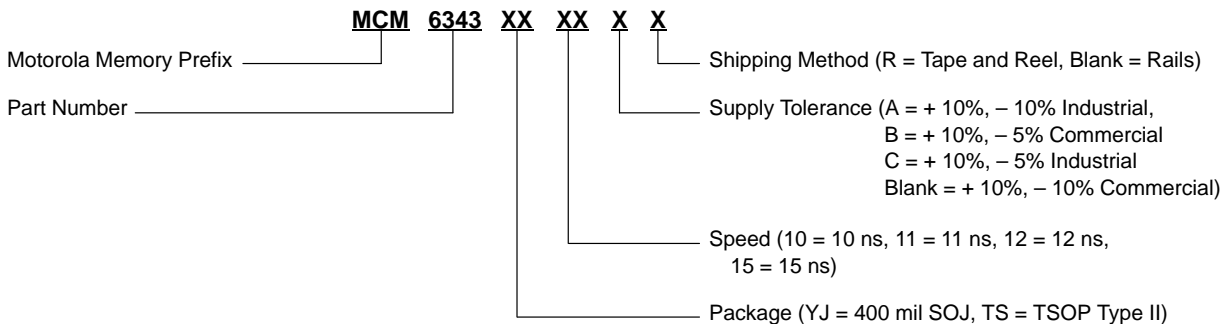
NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. If \bar{G} goes low coincident with or after \bar{W} goes low, the output will remain in a high-impedance state.
4. All write cycle timings are referenced from the last valid address to the first transitioning address.



ORDERING INFORMATION

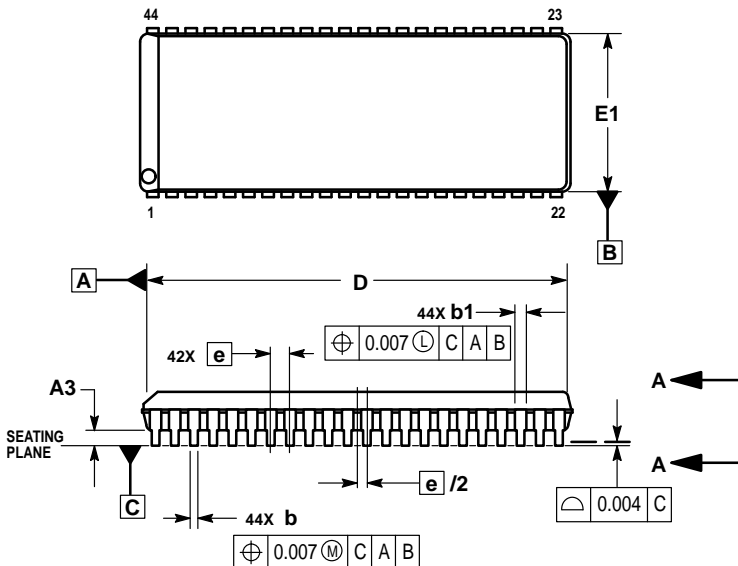
(Order by Full Part Number)



Full Commercial Part Numbers —	MCM6343YJ10B	MCM6343YJ10BR	MCM6343TS10B	MCM6343TS10BR
	MCM6343YJ11	MCM6343YJ11R	MCM6343TS11	MCM6343TS11R
	MCM6343YJ12	MCM6343YJ12R	MCM6343TS12	MCM6343TS12R
	MCM6343YJ15	MCM6343YJ15R	MCM6343TS15	MCM6343TS15R
Full Industrial Part Numbers —	SCM6343YJ11A	SCM6343YJ11AR	SCM6343TS11A	SCM6343TS11AR
	SCM6343YJ12A	SCM6343YJ12AR	SCM6343TS12A	SCM6343TS12AR
	SCM6343YJ15A	SCM6343YJ15AR	SCM6343TS15A	SCM6343TS15AR

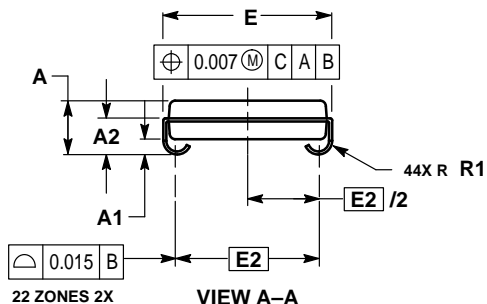
PACKAGE DIMENSIONS

**YJ PACKAGE
44-LEAD
400 MIL SOJ
CASE 919-01**

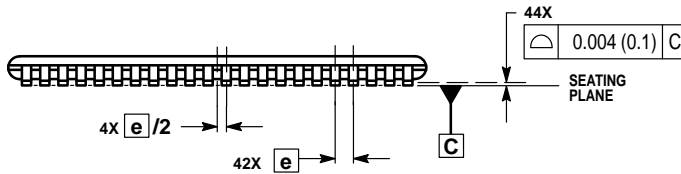
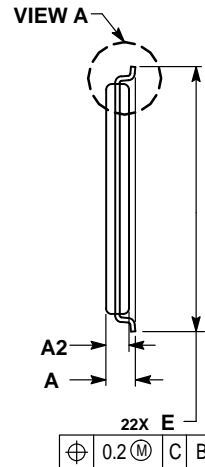
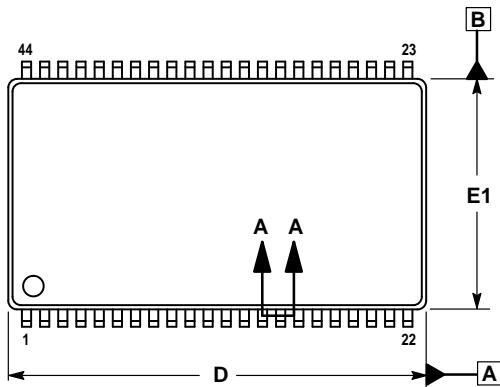


- NOTES:
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 - CONTROLLING DIMENSION: INCH.
 - DIMENSION D DOES NOT INCLUDE MOLD FLASH, TIE BAR BURRS AND GATE BURRS. MOLD FLASH, TIE BAR BURRS AND GATE BURRS SHALL NOT EXCEED 0.006 PER END. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010 PER SIDE.
 - THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM. DIMENSIONS D AND E1 AND, HENCE, DATUMS A AND B, ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
 - DIMENSION b1 DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE SHOULDER WIDTH TO EXCEED b1 MAX BY MORE THAN 0.005. THE DAMBAR INTRUSION(S) SHALL NOT REDUCE THE SHOULDER WIDTH TO LESS THAN 0.001 BELOW b1 MIN.

INCHES		
DIM	MIN	MAX
A	0.128	0.148
A1	0.025	—
A2	0.082	—
A3	0.035	0.045
b	0.015	0.020
b1	0.026	0.032
D	1.120	1.130
E	0.435	0.445
E1	0.395	0.405
E2	0.370 BSC	
e	0.050 BSC	
R1	0.030	0.040



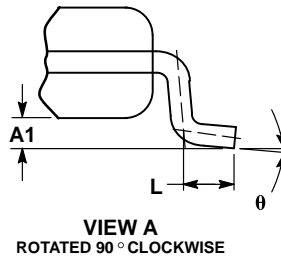
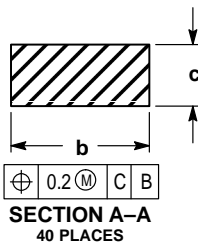
TS PACKAGE
44-LEAD
TSOP TYPE II
CASE 924A-02



NOTES:

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS IN MILLIMETER.
3. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTRUSION IS 0.15 PER SIDE.
4. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSIONS. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.58.

DIM	MILLIMETERS	
	MIN	MAX
A	—	1.20
A1	0.05	0.15
A2	0.95	1.05
b	0.30	0.45
c	0.12	0.21
D	18.28	18.54
e	0.80 BSC	
E	11.56	11.96
E1	10.03	10.29
L	0.40	0.60
θ	0°	5°



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JAPAN: Motorola Japan Ltd.; SPD, Strategic Planning Office, 141,
4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan. 81-3-5487-8488

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; Silicon Harbour Centre,
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